onsemi

PNP General Purpose Transistor

NST857BF3T5G

The NST857BF3T5G device is a spin-off of our popular SOT-23/SOT-323/SOT-563/SOT-963 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-1123 surface mount package. This device is ideal for low-power surface mount applications where board space is at a premium.

Features

- h_{FE}, 220–475
- Low $V_{CE(sat)}$, $\leq -0.3 \text{ V}$
- Reduces Board Space
- This is a Pb–Free Device

MAXIMUM RATINGS

Symbol	Rating	Value	Unit		
V _{CEO}	Collector – Emitter Voltage	-45	Vdc		
V _{CBO}	Collector - Base Voltage	-50	Vdc		
V _{EBO}	BO Emitter – Base Voltage		Vdc		
Ι _C	Collector Current – Continuous	-100	mAdc		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

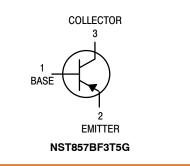
Symbol	Characteristic	Max	Unit		
P _D (Note 1)	Total Device Dissipation, T _A = 25°C Derate above 25°C	290 2.3	mW mW/°C		
R _{θJA} (Note 1)	Thermal Resistance, Junction-to-Ambient	432	°C/W		
P _D (Note 2)	Total Device Dissipation, T _A = 25°C Derate above 25°C	347 2.8	mW mW/°C		
R _{θJA} (Note 2)	Thermal Resistance, Junction-to-Ambient	360	°C/W		
R _{ΨJL} (Note 2)	Thermal Resistance, Junction-to-Lead 3	143	°C/W		
T _J , T _{stg}	Junction and Storage Temperature Range	– 55 to +150	°C		

1. 100 mm² 1 oz, copper traces.

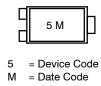
2. 500 mm² 1 oz, copper traces.



CASE 524AA STYLE 1







ORDERING INFORMATION

Device	Package	Shipping [†]
NST857BF3T5G	SOT-1123 (Pb-Free)	8,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

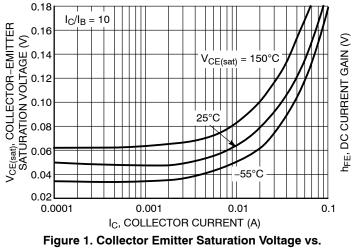
Symbol	Characteristic		Тур	Max	Unit	
OFF CHARAC	OFF CHARACTERISTICS					
V _{(BR)CEO}	Collector – Emitter Breakdown Voltage (I _C = –10 mA)	-45	-	-	V	
V _{(BR)CES}	Collector – Emitter Breakdown Voltage (I _C = –10 μ A, V _{EB} = 0)	-50	-	-	V	
V _{(BR)CBO}	BO Collector – Base Breakdown Voltage ($I_C = -10 \mu A$)		-	-	V	
V _{(BR)EBO}	Emitter – Base Breakdown Voltage (I _E = –1.0 µA)	-5.0	-	-	V	
I _{СВО}	Collector Cutoff Current (V _{CB} = -30 V) (V _{CB} = -30 V, T _A = 150° C)		-	-15 -4.0	nA μA	

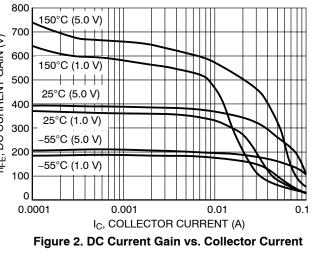
ON CHARACTERISTICS

h _{FE}	DC Current Gain ($I_C = -10 \ \mu A$, $V_{CE} = -5.0 \ V$) ($I_C = -2.0 \ mA$, $V_{CE} = -5.0 \ V$)	_ 220	150 290	- 475	-
V _{CE(sat)}	Collector – Emitter Saturation Voltage ($I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$) ($I_C = -100 \text{ mA}, I_B = -5.0 \text{ mA}$)		-	-0.3 -0.7	V
V _{BE(sat)}	Base – Emitter Saturation Voltage ($I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$) ($I_C = -100 \text{ mA}, I_B = -5.0 \text{ mA}$)		-0.7 -0.9		V
V _{BE(on)}	Base – Emitter On Voltage ($I_C = -2.0 \text{ mA}, V_{CE} = -5.0 \text{ V}$) ($I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ V}$)	-0.6 -	-	-0.75 -0.82	V

SMALL-SIGNAL CHARACTERISTICS

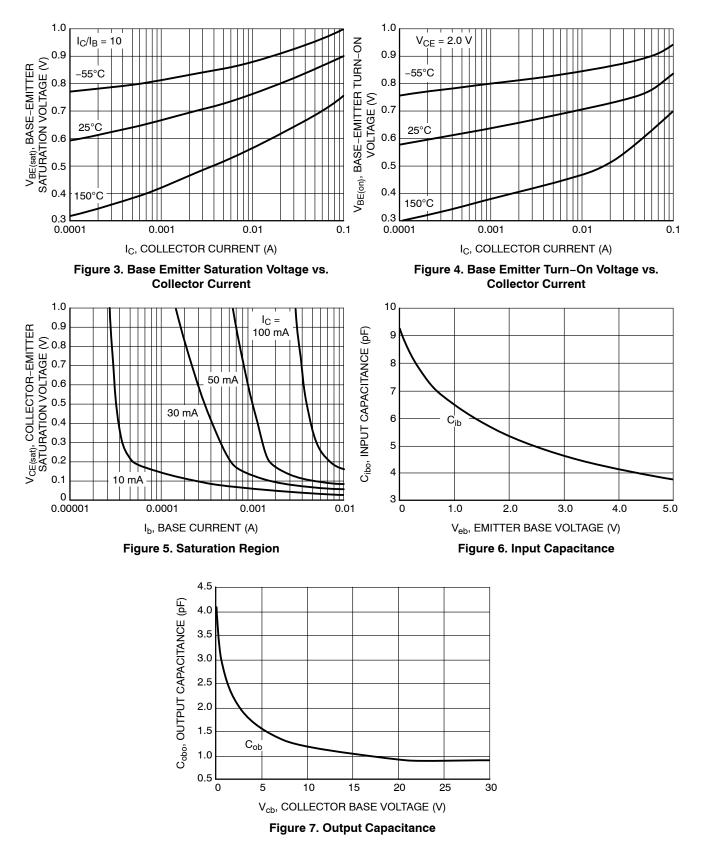
fT	Current – Gain – Bandwidth Product ($I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ Vdc}, f = 100 \text{ MHz}$)	100	-	-	MHz
C _{obo}	Output Capacitance (V _{CB} = -10 V, f = 1.0 MHz)	-	-	4.5	pF
C _{ibo}	Input Capacitance ($V_{EB} = -0.5 \text{ V}, I_C = 0 \text{ mA}, f = 1.0 \text{ MHz}$)	-	-	10	pF
NF	Noise Figure (I_C = -0.2 mA, V_CE = -5.0 Vdc, R_S = 2.0 k\Omega, f = 1.0 kHz, BW = 200 Hz)	-	-	10	dB



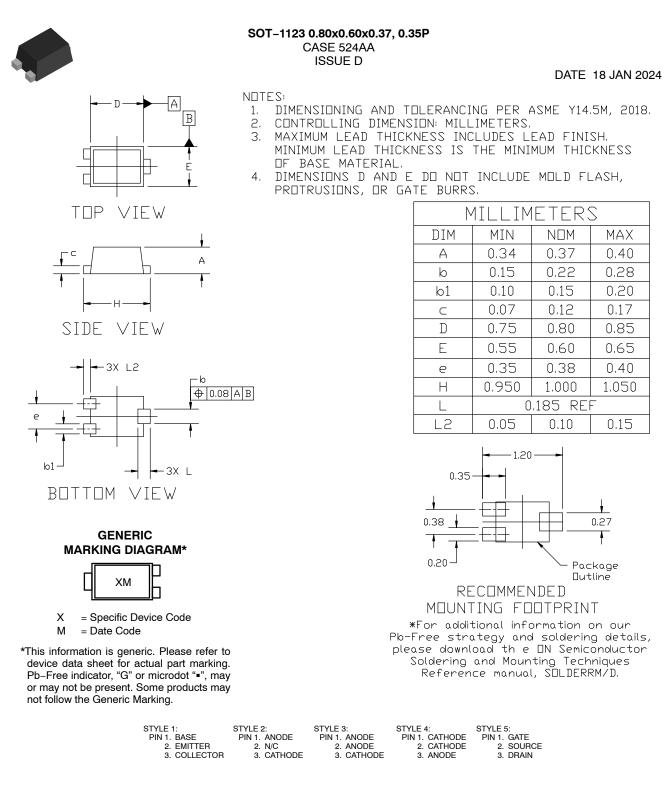




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